

January 2016

# FSA3000 — Two-Port, High-Speed, MHL™ Switch

#### **Features**

- Low On Capacitance: 2.7 pF/4.1 pF MHL/USB (Typical)
- Low Power Consumption: 30 μA Maximum
- MHL Data Rate: 4.92 Gbps (f<sub>3dB</sub> = 2.46 GHz)
- Packaged in 10-Lead MicroPak™
- Over-Voltage Tolerance (OVT) on all USB and MHL Ports; Up to 5.25 V without External Components

### **Applications**

Cell Phones and Digital Cameras

### Description

The FSA3000 is a bi-directional, low-power, two-port, high-speed, USB2.0 and video data switch that supports the Mobile High-Definition Link (MHL) Specification Rev. 2.0. Configured as a double-pole, double-throw (DPDT) switch for data, FSA3000 is optimized for USB2.0 and MHL data sources.

The FSA3000 contains circuitry on the switch I/O pins that allows the device to withstand an over-voltage condition in applications where the  $V_{\rm CC}$  supply is powered off ( $V_{\rm CC}$ =0). The FSA3000 minimizes current consumption even when the voltage applied to the control pins is lower than the supply voltage ( $V_{\rm CC}$ ). This feature is especially valuable in mobile applications, such as cell phones; allowing direct interface with the general-purpose I/Os of the baseband processor. Other applications include switching and connector sharing in portable cell phones, digital cameras, and notebook computers.

### **Ordering Information**

Part Number	Top Mark	Operating Temperature Range	Package
FSA3000L10X	LK		10-Lead, MicroPak <sup>™</sup> 1.6 x 2.1 mm JEDEC MO255B
FSA3000L10X_F131	LK	-40 to +85°C	10-Lead, MicroPak <sup>™</sup> 1.6 x 2.1 mm JEDEC MO255B, Package Rotated 90° in Tape and Reel

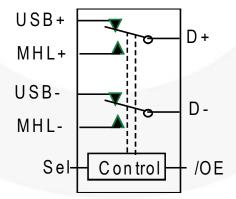


Figure 1. Analog Symbol

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#### **Data Switch Select Truth Table**

SEL <sup>(1)</sup>	/OE <sup>(1)</sup>	Function
Х	HIGH	USB and MHL paths both high impedance
LOW	LOW	D+/D- connected to USB+/USB-
HIGH	LOW	D+/D- connected to MHL+/MHL-

#### Note:

1. Control inputs should never be left floating or unconnected.

## **Pin Configurations**

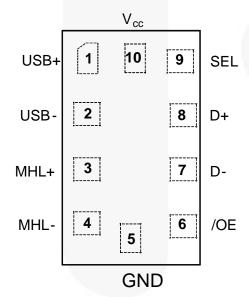


Figure 2. Pin Assignments (Top-Through View)

### **Pin Definitions**

Pin#	Name	Description
1	USB+	USB Differential Data (Positive)
2	USB-	USB Differential Data (Negative)
3	MHL+	MHL Differential Data (Positive)
4	MHL-	MHL Differential Data (Negative)
5	GND	Ground
6	/OE	Output Enable (Active LOW)
7	D-	Data Switch Output (Negative)
8	D+	Data Switch Output (Positive)
9	SEL	Data Switch Select
10	V <sub>CC</sub>	Supply

### **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter		Min.	Max.	Unit
V <sub>CC</sub>	Supply Voltage		-0.5	5.5	V
V <sub>CNTRL</sub>	DC Input Voltage (SEL, /OE) <sup>(2)</sup>		-0.5	Vcc	V
V <sub>SW</sub>	DC Switch I/O Voltage <sup>(2,3)</sup>		-0.50	5.25	V
I <sub>IK</sub>	DC Input Diode Current		-50		mA
I <sub>OUT</sub>	DC Output Current			100	mA
T <sub>STG</sub>	Storage Temperature		-65	+150	°C
MSL	Moisture Sensitivity Level (JEDEC J-STD-020A)			1	
	Human Body Model, JEDEC: JESD22-A114	All Pins	/	3.5	
ESD	IEC 61000-4-2, Level 4, for D+/D- and V <sub>CC</sub> Pins <sup>(4)</sup>	Contact		8	kV
E9D	IEC 61000-4-2, Level 4, for D+/D- and V <sub>CC</sub> Pins <sup>(4)</sup>	Air		15	ĸ۷
	Charged Device Model, JESD22-C101			2	

#### Notes:

- 2. The input and output negative ratings may be exceeded if the input and output diode current ratings are observed.
- 3. V<sub>SW</sub> refers to analog data switch paths (USB and MHL).
- 4. Testing performed in a system environment using TVS diodes.

### **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
V <sub>CC</sub>	Supply Voltage	2.7	4.3	V
t <sub>RAMP(VCC)</sub>	Power Supply Slew Rate	100	1000	µs/V
$V_{CNTRL}$	Control Input Voltage (SEL, /OE) <sup>(5)</sup>	0	4.3	V
$\Theta_{JA}$	Thermal Resistance		313	C°/W
V <sub>SW(USB)</sub>	Switch I/O Voltage (USB Switch Path)	-0.5	3.6	V
V <sub>SW(MHL)</sub>	Switch I/O Voltage (MHL Switch Path)	1.65	3.45	V
T <sub>A</sub>	Operating Temperature	-40	+85	°C

#### Note:

5. The control inputs must be held HIGH or LOW; they must not float.

### **DC Electrical Characteristics**

All typical value are at T<sub>A</sub>=25°C unless otherwise specified.

Ols al	Damamatan	O a malitia m	V 00	T <sub>A</sub> = -4	11		
Symbol	Parameter	Condition	V <sub>cc</sub> (V)	Min.	Тур.	Max.	Unit
V <sub>IK</sub>	Clamp Diode Voltage	I <sub>IN</sub> =-18 mA	2.7			-1.2	V
V <sub>IH</sub>	Control Input Voltage High	SEL, /OE	2.7 to 4.3	1.25			V
V <sub>IL</sub>	Control Input Voltage Low	SEL, /OE	2.7 to 4.3			0.6	V
I <sub>IN</sub>	Control Input Leakage	V <sub>SW</sub> =0 to 3.6 V, V <sub>CNTRL</sub> =0 to V <sub>CC</sub>	4.3	-500		500	nA
I <sub>OZ(MHL)</sub>	Off-State Leakage for Open MHLn Data Paths	$V_{SW}$ =1.65 $\leq$ MHL $\leq$ 3.45 V	4.3	-500		500	nA
I <sub>OZ(USB)</sub>	Off-State Leakage for Open USBn Data Paths	V <sub>SW</sub> =0 ≤ USB ≤ 3.6 V	4.3	-500		500	nA
I <sub>CL(MHL)</sub>	On-State Leakage for Closed MHLn Data Paths <sup>(6)</sup>	$V_{SW}$ =1.65 $\leq$ MHL $\leq$ 3.45 V	4.3	-500		500	nA
I <sub>CL(USB)</sub>	On-State Leakage for Closed USBn Data Paths <sup>(6)</sup>	V <sub>SW</sub> =0 ≤ USB ≤ 3.6 V	4.3	-500		500	nA
l <sub>OFF</sub>	Power-Off Leakage Current (All I/O Ports)	V <sub>SW</sub> =0 V or 3.6 V, Figure 4	0	-500		500	nA
R <sub>ON(USB)</sub>	HS Switch On Resistance (USB to Dn Path)	V <sub>SW</sub> =0.4 V, I <sub>ON</sub> =-8 mA, Figure 3	2.7		3.5	4.8	Ω
R <sub>ON(MHL)</sub>	HS Switch On Resistance (MHL to Dn Path)	V <sub>SW</sub> =V <sub>CC</sub> -1050 mV, I <sub>ON</sub> =-8 mA, Figure 3	2.7		4.7	6.0	Ω
$\Delta R_{\text{ON(MHL)}}$	Difference in R <sub>ON</sub> Between MHL Positive-Negative	V <sub>SW</sub> =V <sub>CC</sub> -1050 mV, I <sub>ON</sub> =-8 mA, Figure 3,	2.7		0.03		Ω
$\Delta R_{\text{ON(USB)}}$	Difference in R <sub>ON</sub> Between USB Positive-Negative	V <sub>SW</sub> =0.4V, I <sub>ON</sub> =-8mA, Figure 3	2.7		0.18		Ω
R <sub>ONF(MHL)</sub>	Flatness for R <sub>ON</sub> MHL Path	V <sub>SW</sub> =1.65 to 3.45 V, I <sub>ON</sub> =-8 mA, Figure 3	2.7		0.9		Ω
Icc	Quiescent Supply Current	$V_{/OE}$ =0, $V_{SEL}$ =0 or $V_{CC}$ , $I_{OUT}$ =0	4.3	A		30	μA
I <sub>CCZ</sub>	Quiescent Supply Current (High Impedance)	V <sub>SEL</sub> =X, V <sub>/OE</sub> =V <sub>CC</sub> , I <sub>OUT</sub> =0	4.3			1	μA
I <sub>CCT</sub>	Increase in Quiescent Supply Current	V <sub>SEL</sub> =X, V <sub>/OE</sub> =1.65 V	4.3	_	5	10	μA

#### Note:

6. For this test, the data switch is closed with the respective switch pin floating.

## **AC Electrical Characteristics**

All typical value are for  $V_{\text{CC}} {=} 3.3 \text{ V}$  and  $T_{\text{A}} {=} 25^{\circ}\text{C}$  unless otherwise specified.

Symbol	Parameter	Condition	V <sub>cc</sub> (V)	T <sub>A</sub>	Unit		
				Min.	Тур.	Max.	
t <sub>ON</sub>	MHL Turn-On Time, SEL to Output	$R_L$ =50 $\Omega$ , $C_L$ =5 pF, $V_{SW(USB)}$ =0.8 V, $V_{SW(MHL)}$ =3.3 V, Figure 5, Figure 6	2.7 to 3.6 V		350	600	ns
t <sub>OFF</sub>	MHL Turn-Off Time, SEL to Output	$R_L$ =50 $\Omega$ , $C_L$ =5 pF, $V_{SW(USB)}$ =0.8 V, $V_{SW(MHL)}$ =3.3 V, Figure 5, Figure 6	2.7 to 3.6 V		125	300	ns
t <sub>ZHM,ZLM</sub>	MHL Enable Time, /OE to Output	$R_L$ =50 $\Omega$ , $C_L$ =5 pF, $V_{SW(MHL)}$ =3.3 V, Figure 5, Figure 6	2.7 to 3.6 V		60	150	μs
t <sub>zhu,zLu</sub>	USB Enable Time, /OE to Output	$R_L$ =50 $\Omega$ , $C_L$ =5 pF, $V_{SW(USB)}$ =0.8 V, Figure 5, Figure 6	2.7 to 3.6 V		100	300	ns
t <sub>LZM,HZM</sub>	MHL Disable Time, /OE to Output	R <sub>L</sub> =50 $\Omega$ , C <sub>L</sub> =5 pF, V <sub>SW(MHL)</sub> =3.3 V, Figure 5, Figure 6	2.7 to 3.6 V		35	100	ns
t <sub>LZU,HZU</sub>	USB Disable Time, /OE to Output	$R_L$ =50 $\Omega$ , $C_L$ =5 pF, $V_{SW(USB)}$ =0.8 V, Figure 5, Figure 6	2.7 to 3.6 V		35	100	ns
t <sub>PD</sub>	Propagation Delay <sup>(7)</sup>	C <sub>L</sub> =5 pF, R <sub>L</sub> =50 Ω, Figure 5, Figure 7	2.7 to 3.6 V		0.25		ns
t <sub>BBM</sub>	Break-Before-Make <sup>(7)</sup>	$R_L$ =50 $\Omega$ , $C_L$ =5 pF, $V_{ID}$ = $V_{MHL}$ =3.3 $V$ , $V_{USB}$ = 0.8 $V$ , Figure 9	2.7 to 3.6 V	2		13	ns
O <sub>IRR(MHL)</sub>	Off loalation <sup>(7)</sup>	$V_{S}\text{=}1~V_{pk\text{-}pk},~R_{L}\text{=}50~\Omega,~f\text{=}240~MHz,}$ Figure 11	2.7 to 3.6 V		-55		dB
O <sub>IRR(USB)</sub>	- Oil isolation	$V_{\text{S}}\!\!=\!\!400~\text{mV}_{\text{pk-pk}},R_{\text{L}}\!\!=\!\!50~\Omega,\text{f=}240~\text{MHz},$ Figure 11	2.7 to 3.6 V		-45		dB
Xtalk <sub>MHL</sub>	Non-Adjacent	$V_{\text{S}}\text{=-}1~V_{\text{pk-pk}},~R\text{=-}50~\Omega,~\text{f=-}240~\text{MHz},$ Figure 12	2.7 to 3.6 V		-47		dB
Xtalk <sub>USB</sub>	Channel <sup>(7)</sup> Crosstalk	$V_S$ =400 m $V_{pk-pk}$ , R <sub>L</sub> =50 $\Omega$ , f=240 MHz, Figure 12	2.7 to 3.6 V		-45		dB
BW	MHL Enable Time, /OE to Output  USB Enable Time, /OE to Output  USB Enable Time, /OE to Output  MHL Disable Time, /OE to Output  USB Disable Time, /OE to Output  USB Disable Time, /OE to Output  The Propagation Delay  Break-Before-Make  RR(MHL)  Off Isolation  Off Isolation  Non-Adjacent Channel  Channel  Off Bandwidth  Differential -3db Bandwidth  OSB Crosstalk  Differential -3db Bandwidth  OSB Crosstalk	$V_{\text{IN}}$ =1 $V_{\text{pk-pk}}$ , MHL Path, $R_{\text{L}}$ =50 $\Omega$ , $C_{\text{L}}$ =0 Pf, Figure 10, Figure 15	2.7 to	(	2.46	Į.	GHz
Loss)	-3db Bandwidth <sup>(/)</sup>	$V_{\text{IN}}$ =400 m $V_{\text{pk-pk}}$ , USB Path, R <sub>L</sub> =50 Ω, C <sub>L</sub> =0 pF, Figure 10, Figure 16	3.6 V		1.22		GIIZ

#### Note:

7. Guaranteed by characterization.

## **USB High-Speed AC Electrical Characteristics**

Typical values are for  $V_{CC}$ =3.3 V and  $T_A$ =25°C unless otherwise specified.

Symbol	Parameter	Condition	V <sub>cc</sub> (V)	Тур.	Unit
t <sub>SK(P)</sub>	Skew of Opposite Transitions of the Same Output <sup>(8)</sup>	$C_L=5$ pF, $R_L=50$ $\Omega$ , Figure 8	3.0 to 3.6	6	ps
t <sub>J</sub>	Total Jitter <sup>(8)</sup>	$R_L$ =50 $\Omega$ , $C_L$ =5 pf, $t_R$ = $t_F$ =500 ps (10-90%) at 480 Mbps, PN7	3.0 to 3.6	15	ps

#### Note:

8. Guaranteed by characterization.

## **MHL AC Electrical Characteristics**

Typical values are for  $V_{CC}$ =3.3 V and  $T_A$ =25°C unless otherwise specified.

Symbol	Parameter	Condition	V <sub>cc</sub> (V)	Тур.	Unit
t <sub>SK(P)</sub>	Skew of Opposite Transitions of the Same Output <sup>(9)</sup>	R <sub>PU</sub> =50 $\Omega$ to V <sub>CC</sub> , C <sub>L</sub> =0 pF	3.0 to 3.6 V	6	ps
tu	Total Jitter <sup>(9)</sup>	f=2.25 Gbps, PN7, R <sub>PU</sub> =50 $\Omega$ to V <sub>CC</sub> , C <sub>L</sub> =0 pF	3.0 to 3.6 V	15	ps

#### Note:

9. Guaranteed by characterization.

## Capacitance

Typical values are for V<sub>CC</sub>=3.3 V and T<sub>A</sub>=25°C unless otherwise specified.

Symbol	Parameter	Condition	Тур.	Max.	Unit
C <sub>IN</sub>	Control Pin Input Capacitance <sup>(10)</sup>	V <sub>CC</sub> =0 V, f=1 MHz	2.1		pF
C <sub>ON(USB)</sub>	USB Path On Capacitance <sup>(10)</sup>	V <sub>CC</sub> =3.3 V, f=240 MHz, Figure 14	4.1	5.0	pF
C <sub>OFF(USB)</sub>	USB Path Off Capacitance <sup>(10)</sup>	V <sub>CC</sub> =3.3 V, f=240 MHz, Figure 13	2.8	3.2	pF
C <sub>ON(MHL)</sub>	MHL Path On Capacitance <sup>(10)</sup>	V <sub>CC</sub> =3.3 V, f=240 MHz, Figure 14	2.7	3.0	pF
C <sub>OFF(MHL)</sub>	MHL Path Off Capacitance <sup>(10)</sup>	V <sub>CC</sub> =3.3 V, f=240 MHz, Figure 13	1.1	1.5	pF

#### Note:

10. Guaranteed by characterization, not production tested.

### **Test Diagrams**

#### Note:

11. HSD refers to the high-speed data on USB or MHL paths.

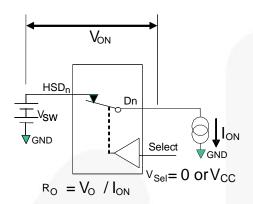
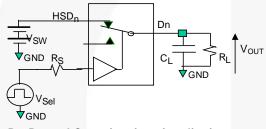
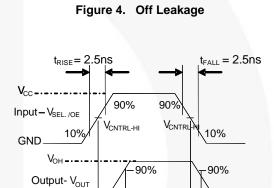


Figure 3. On Resistance



 $R_L\,,\,R_S\,$  and  $C_L\,$  are function of application environment (see AC Tables for specific values)  $C_L\,$  includes test fixture and stray capacitance

Figure 5. AC Test Circuit Load



\*\*Each switch port is tested separately

I<sub>Dn(OFF)</sub>

Select

v<sub>Sel</sub>= 0 orVcc

NC

Figure 6. Turn-On / Turn-Off Waveforms

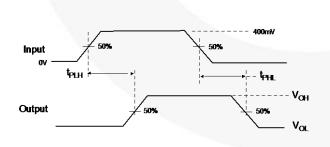


Figure 7. Propagation Delay ( $t_Rt_F$  – 500 ps)

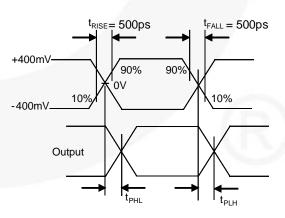
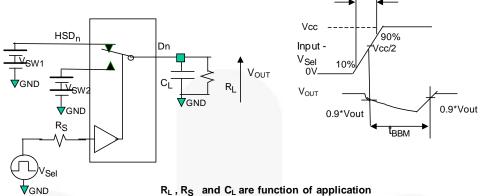


Figure 8. Intra-Pair Skew Test t<sub>SK(P)</sub>

## Test Diagrams (Continued)



environment (see AC Tables for specific values)
C<sub>L</sub> includes test fixture and stray capacitance

 $t_{RISE} = 2.5$ ns

Figure 9. Break-Before-Make Interval Timing

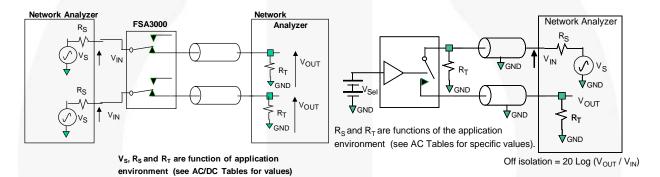


Figure 10. Insertion Loss

Figure 11. Channel Off Isolation

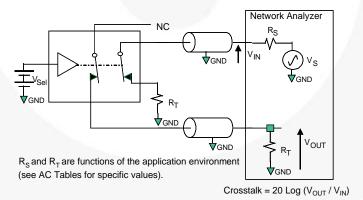
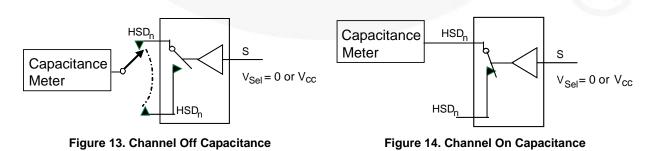


Figure 12. Non-Adjacent Channel-to-Channel Crosstalk



#### **Insertion Loss**

One of the key factors for the FSA3000 in mobile digital video applications is the small amount of insertion loss in the received signal as it passes through the switch. This results in minimal degradation of the received eye. One of the ways to measure the quality of the high data rate channels is using balanced ports and 4-port differential S-parameter analysis, particularly SDD21.

Bandwidth is measured using the S-parameter SDD21 methodology. Figure 15 shows the bandwidth (GHz) for the MHL path and Figure 16 shows the bandwidth curve for the USB path.

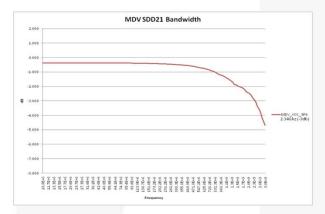


Figure 15. MHL (MDV) Path SDD21 Insertion Loss Curve

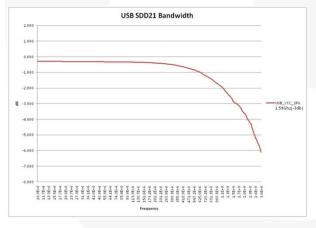


Figure 16. USB Path SDD21 Insertion Loss Curve

## **Typical Application**

Figure 17 shows a typical mobile application using the FSA3000 for MHL switching. The FSA3157 is used for OTG dual-role device implementations where the CBUS of MHL and the ID pin for USB needs to be switched. The 3M resistor for MHL\_SEL is optional to ensure that on power up the USB switch path is selected as default.

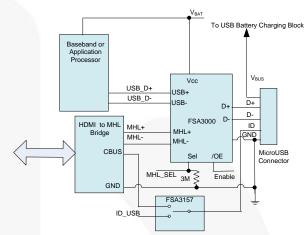


Figure 17. Typical Mobile MHL Application

#### **Packing Specifications**

### MicroPak 1.6x2.1 F131, Packing Drawing



#### Packing Description:

MicroPak 1.6x2.1 F131 products are classified under Moisture Sensitive Level 1.

The carrier tape is made from dissipative polystyrene or polycarbonate resin. The cover tape is a multilayer film primarily composed of polyester film, adhesive layer, heat activated sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 5000 units per 178 mm diameter reel. Up to three reels are packed in each intermediate box. The reels is made of polystyrene plastic (anti-static coated or intrinsic).

These full reels are individually barcode labeled and placed inside a pizza box made of recyclable corrugated brown paper with a Fairchild logo printing. Up to 3 reels could be packed in the pizza box. And these pizza boxes are placed inside a barcode labeled shipping box which comes in different sizes depending on the number of parts shipped.

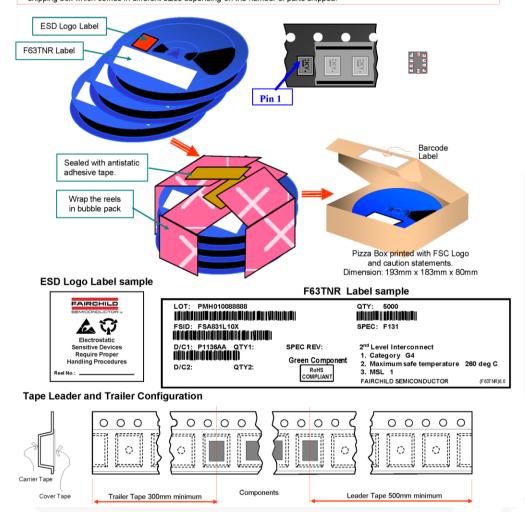
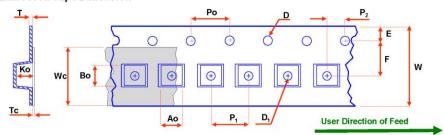


Figure 18. MicroPak<sup>™</sup> 1.6 x 2.1 mm, Packing Drawing, Page 1

## Packing Specifications (Continued)

#### **Embossed Tape Dimension**



#### Dimensions are in millimeters

Package	Ao	Bo	D	D <sub>1</sub>	E	F	Ko	P <sub>1</sub>	Po	P <sub>2</sub>	T	Tc	W	Wc
	+/-0.05	+/-0.05	+/-0.10	min.	+/-0.1	+/-0.1	+/-0.05	TYP	TYP	+/-0/05	TYP	+/-0.005	+/-0.3	TYP
MAC10A	1.83	2.34	1.5	0.5	1.75	3.5	0.65	4	4	2.0	0.254	0.06	8	5.3

Notes: Ao, Bo, and Ko dimensions are determined with respect to the EIA /Jedec RS-481 rotational and lateral movement requirements (see sketches A, B, and C).

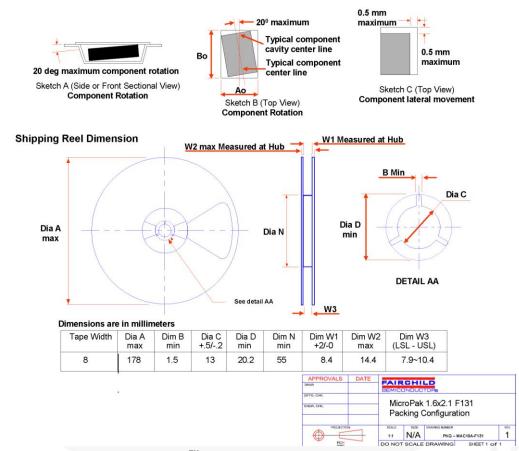
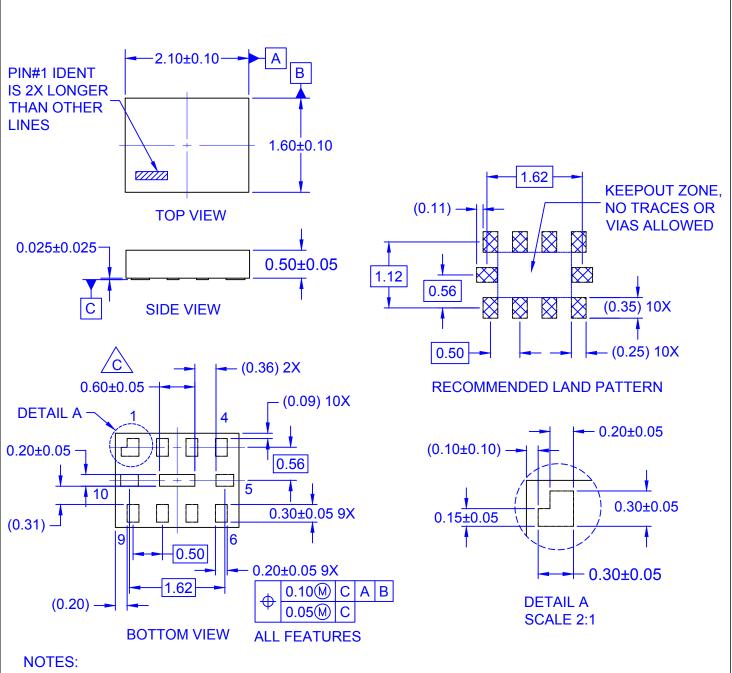


Figure 19. MicroPak<sup>™</sup> 1.6 x 2.1 mm, Packing Drawing, Page 2



- A. PACKAGE CONFORMS TO JEDEC REGISTRATION MO-255, VARIATION UABD.
- **B. DIMENSIONS ARE IN MILLIMETERS.**
- PRESENCE OF CENTER PAD IS PACKAGE SUPPLIER DEPENDENT. IF PRESENT IT IS NOT INTENDED TO BE SOLDERED AND HAS A BLACK OXIDE FINISH.
- D. DRAWING FILENAME: MKT-MAC10ArevG.
- E. DIMENSIONS WITHIN ( ) ARE UNCONTROLLED.

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